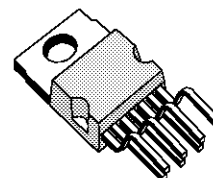


VERTICAL DEFLECTION OUTPUT CIRCUIT

- POWER AMPLIFIER
- FLYBACK GENERATOR
- THERMAL PROTECTION

DESCRIPTION

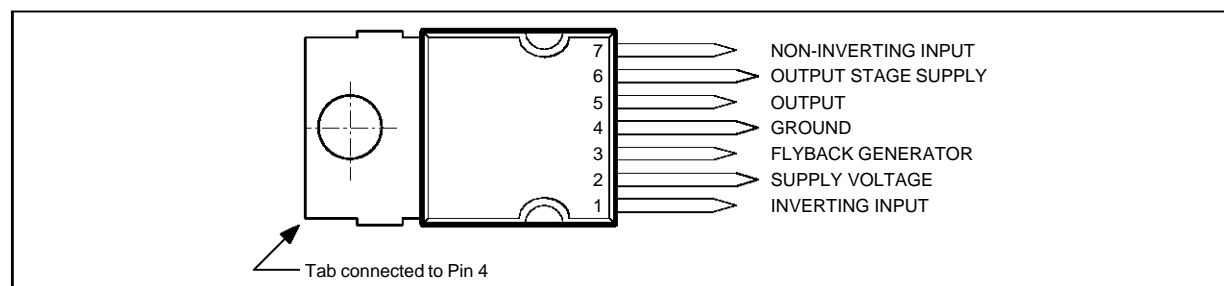
The TDA9302H is a monolithic integrated circuit in HEPTAWATT™ package. It is a high efficiency power booster for direct driving of vertical windings of TV yokes. It is intended for use in Color and B & W television as well as in monitors and displays.



HEPTAWATT
(Plastic Package)

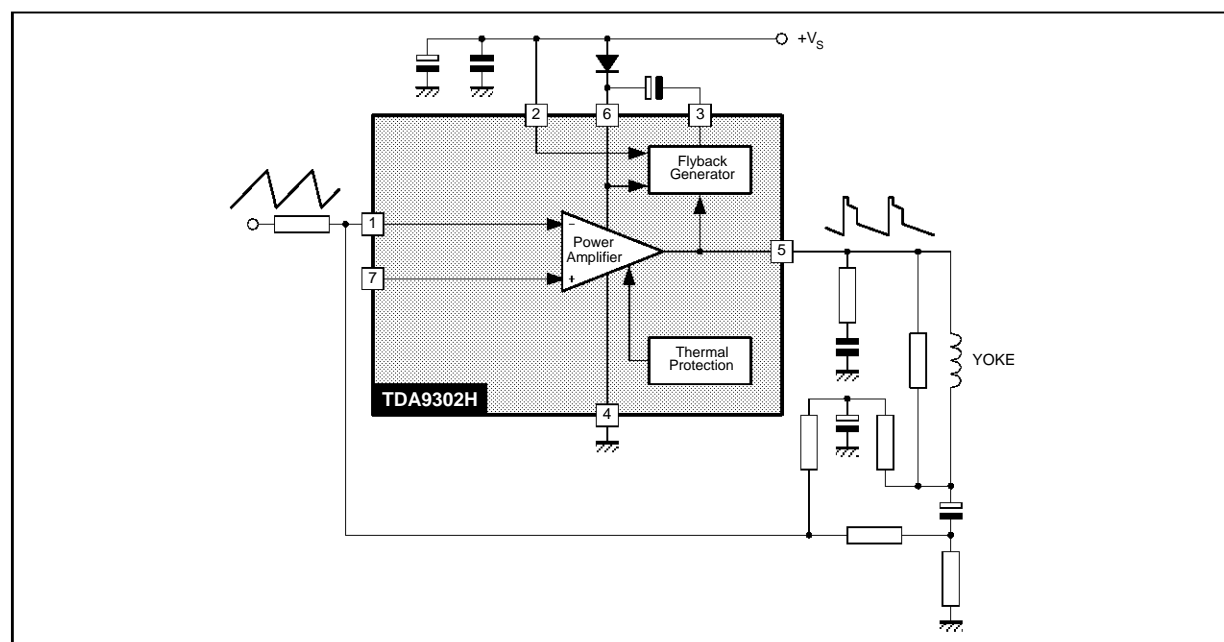
ORDER CODE : TDA9302H

PIN CONNECTIONS (top view)



9302H-01.EPS

BLOCK DIAGRAM



9302H-02.EPS

ABSOLUTE MAXIMUM RATINGS AT $T_A = 25^\circ\text{C}$

Symbol	Parameter	Value	Unit
V_S	Supply Voltage (pin 2)	35	V
V_5, V_6	Flyback Peak Voltage	60	V
V_3	Voltage at Pin 3	+ V_S	
V_1, V_7	Amplifier Input Voltage	+ V_S – 0.5	V
I_o	Deflection Output Current	± 1.8	A
I_3	Pin 3 DC Current at $V_5 < V_2$	100	mA
P_{tot}	Total Power Dissipation at $T_{case} = 90^\circ\text{C}$	15	W
T_{stg}, T_j	Storage and Junction Temperature	– 40, +150	$^\circ\text{C}$

9302H-01.TBL

THERMAL DATA

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Thermal Resistance Junction-case	Max. 4	$^\circ\text{C/W}$

9302H-02.TBL

RECOMMENDED OPERATING CHARACTERISTICS AT $T_A = 25^\circ\text{C}$

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_{2M}	Recommended Supply Voltage			25		V
V_{2R}	Operating Supply Voltage Range		15		30	V
I_{5PP}	Deflection Output Current				2	App

9302H-03.TBL

ELECTRICAL CHARACTERISTICS

(refer to the test circuits, $V_S = 35\text{V}$, $T_{amb} = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit	Fig.
I_2	Pin 2 Quiescent Current	$I_3 = 0, I_5 = 0$			16	mA	1a
I_6	Pin 6 Quiescent Current	$I_3 = 0, I_5 = 0$			36	mA	1a
I_1	Amplifier Input Bias Current	$V_1 = 1\text{ V}, V_7 = 2\text{ V}$		– 0.1	– 1	μA	1a
		$V_1 = 2\text{ V}, V_7 = 1\text{ V}$		– 0.1	– 1	μA	1a
V_{3L}	Pin 3 Saturation Voltage to GND	$I_3 = 20\text{ mA}$		1	1.5	V	1c
V_5	Quiescent Output Voltage	$V_S = 35\text{V}, R_a = 39\text{ k}\Omega$		18		V	1d
V_{5L}	Output Saturation Voltage to GND	$I_5 = 1\text{ A}$		0.9	1.3	V	1c
		$I_5 = 0.7\text{ A}$		0.7	1	V	1c
V_{5H}	Output Saturation Voltage to Supply	– $I_5 = 1\text{ A}$		1.5	2	V	1b
		– $I_5 = 0.7\text{ A}$		1.3	1.8	V	1b
T_j	Junction Temperature for Thermal Shut Down			140		$^\circ\text{C}$	

9302H-04.TBL

Figure 1 a : Measurement of l_1 ; l_2 ; l_6

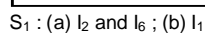


Figure 1 b : Measurement of V_{5H}



Figure 1 c : Measurement of V_{3L} ; V_{5L}

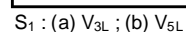


Figure 1 d : Measurement of V_5

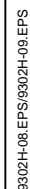




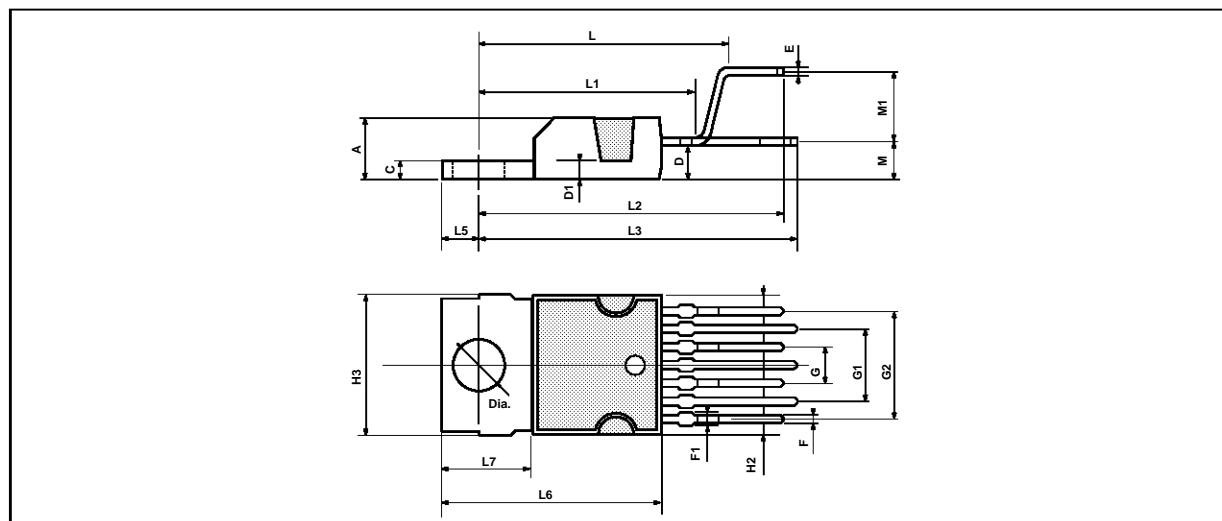
The power dissipated in the circuit must be removed by adding an external heatsink. Thanks to the HEPTAWATTTM package attaching the heatsink is very simple, a screw or a compression spring (clip) being sufficient.

Between the heatsink and the package it is better to insert a layer of silicon grease, to optimize the thermal contact ; no electrical isolation is needed between the two surfaces, since the tab is connected to Pin 4 which is ground.

Figure 3 : Mounting Examples



PACKAGE MECHANICAL DATA : 9 PINS - PLASTIC HEPTAWATT



PM-HEPTV.EPS

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			4.8			0.189
C			1.37			0.054
D	2.4		2.8	0.094		0.110
D1	1.2		1.35	0.047		0.053
E	0.35		0.55	0.014		0.022
F	0.6		0.8	0.024		0.031
F1			0.9			0.035
G	2.41	2.54	2.67	0.095	0.100	0.105
G1	4.91	5.08	5.21	0.193	0.200	0.205
G2	7.49	7.62	7.8	0.295	0.300	0.307
H2			10.4			0.409
H3	10.05		10.4	0.396		0.409
L		16.97			0.668	
L1		14.92			0.587	
L2		21.54			0.848	
L3		22.62			0.891	
L5	2.6		3	0.102		0.118
L6	15.1		15.8	0.594		0.622
L7	6		6.6	0.236		0.260
M		2.8			0.110	
M1		5.08			0.200	
Dia.	3.65		3.85	0.144		0.152

HEPTV.TBL

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